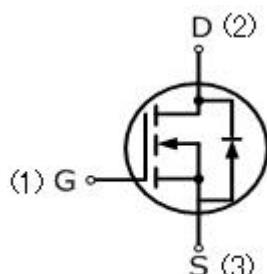


20N50Y

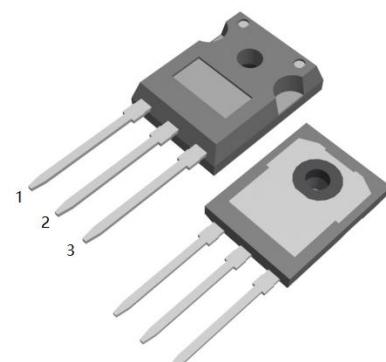
20 Amps, 500 Volts N-CHANNEL Power MOSFET

FEATURE

- 20A, 500V, $R_{DS(ON)}\text{MAX}=0.32 \Omega$ @ $V_{GS}=10V/10A$
- Low gate charge
- Low C_{iss}
- Fast switching
- 100% avalanche tested
- Improved dv/dt capability



TO-247-3L



Absolute Maximum Ratings ($T_c=25^\circ\text{C}$, unless otherwise noted)

Parameter	Symbol	20N50Y	UNIT
Drain-Source Voltage	V_{DSS}	500	V
Gate-Source Voltage	V_{GS}	± 30	
Continuous Drain Current	I_D	20	A
Pulsed Drain Current (Note 1)	I_{DM}	80	
Single Pulse Avalanche Energy (Note 2)	E_{AS}	675	mJ
Reverse Diode dV/dt (Note 3)	dV/dt	5	V/ns
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 to +150	°C
Maximum lead temperature for soldering purposes, 1/8" from case for 5 seconds	T_L	260	°C

Parameter	Symbol	20N50Y	Units
Thermal resistance, Channel to Case	$R_{th(ch-c)}$	0.5	°C/W
Maximum Power Dissipation	$T_c=25^\circ\text{C}$	P_D	W

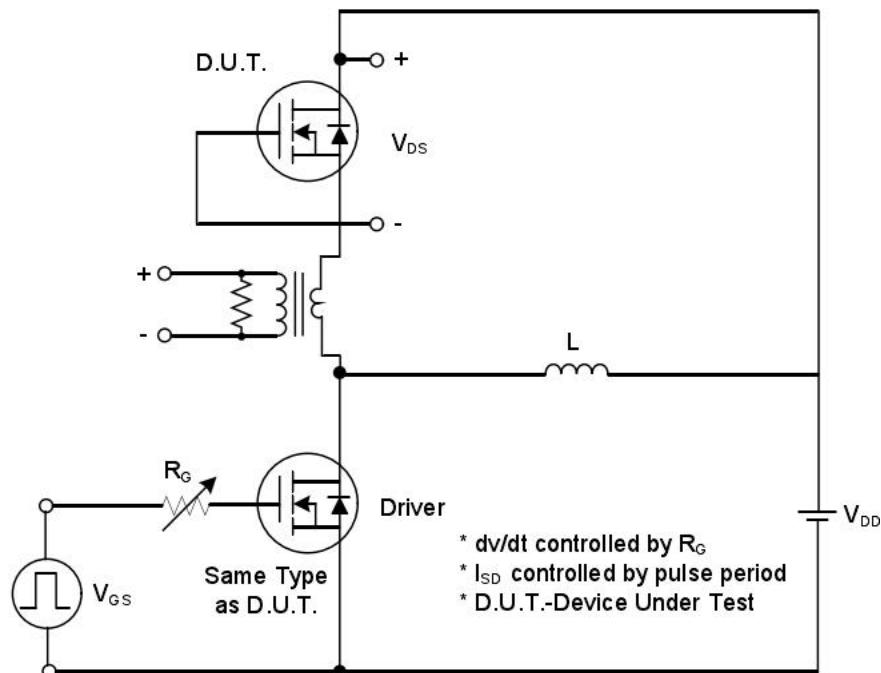
Electrical Characteristics (T_c=25°C,unless otherwise noted)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V,I _D =250uA	500	—	—	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =500V,V _{GS} =0V	—	—	1	uA
Gate-Body Leakage Current,Forward	I _{GSSF}	V _{GS} =30V,V _{DS} =0V	—	—	100	nA
Gate-Body Leakage Current,Reverse	I _{GSSR}	V _{GS} =-30V,V _{DS} =0V	—	—	-100	nA
On Characteristics						
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =250uA	2.0	—	4.0	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V,I _D =10A	—	0.256	0.32	Ω
Dynamic Characteristics						
Input Capacitance	C _{iss}	V _{DS} =25V,V _{GS} =0V, f=1.0MHZ	—	3235	—	pF
Output Capacitance	C _{oss}		—	243	—	pF
Reverse Transfer Capacitance	C _{rss}		—	61	—	pF
Switching Characteristics						
Turn-On Delay Time	t _{d(on)}	V _{DD} =250V,I _D =18A, R _G =10Ω	—	27.8	—	ns
Turn-On Rise Time	t _r		—	5.8	—	ns
Turn-Off Delay Time	t _{d(off)}		—	77.4	—	ns
Turn-Off Fall Time	t _f		—	8.4	—	ns
Total Gate Charge	Q _g	V _{DS} =400V,I _D =18A, V _{GS} =10V	—	52	—	nC
Gate-Source Charge	Q _{gs}		—	13	—	nC
Gate-Drain Charge	Q _{gd}		—	19	—	nC
Drain-Source Body Diode Characteristics and Maximum Ratings						
Diode Forward Voltage	V _{SD}	I _S =1A,V _{GS} =0V	—	—	1.2	V
Reverse Recovery Time	t _{rr}	V _{DS} =30V,I _S =1A, dI _F /dt=100A/us,(Note3)	—	553	—	ns
Reverse Recovery Charge	Q _{rr}		—	6.0	—	uC

Notes

1. Repetitive Rating:pulse width limited by maximum junction temperature.
2. V_{DD}=100V,L=10mH,R_g=25Ω, starling T_J=25°C.
3. Pulse width≤300us;duty cycle≤2%.

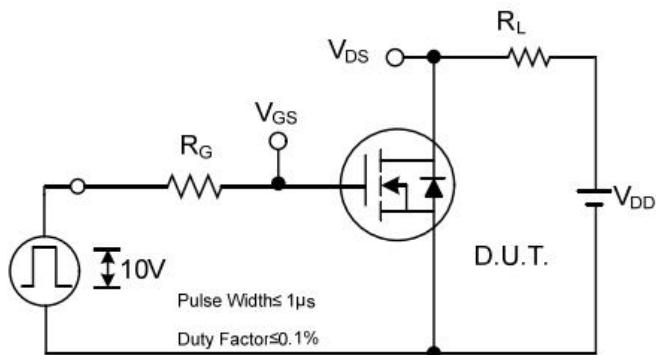
RATING AND CHARACTERISTIC CURVES



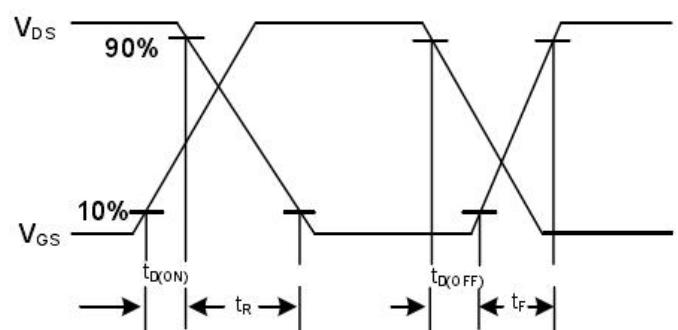
Peak Diode Recovery dv/dt Test Circuit



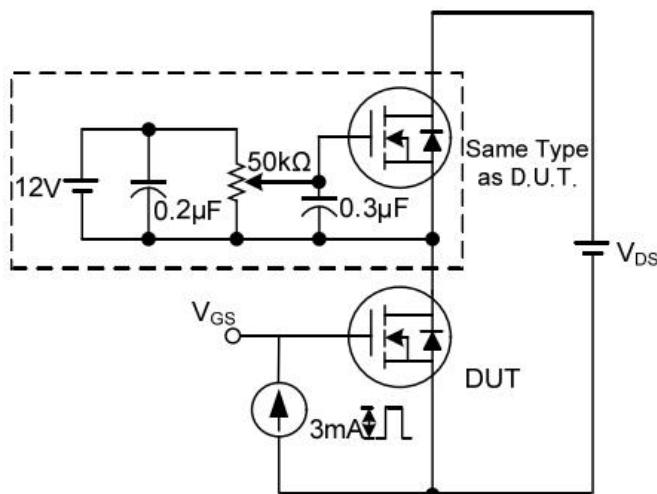
Peak Diode Recovery dv/dt Waveforms



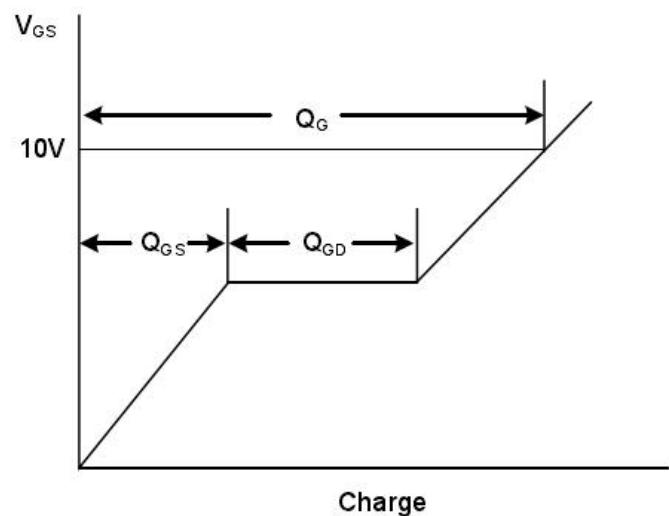
Switching Test Circuit



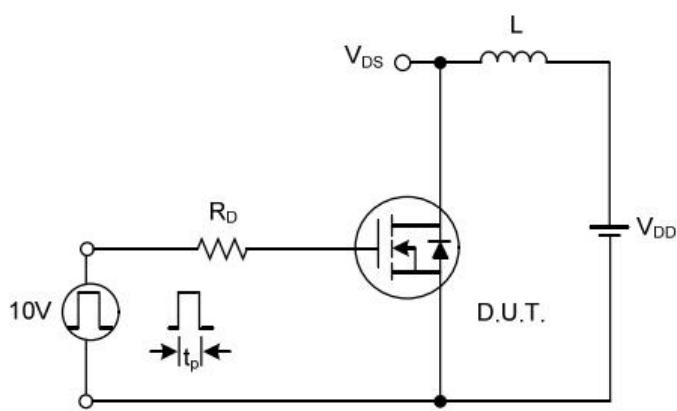
Switching Waveforms



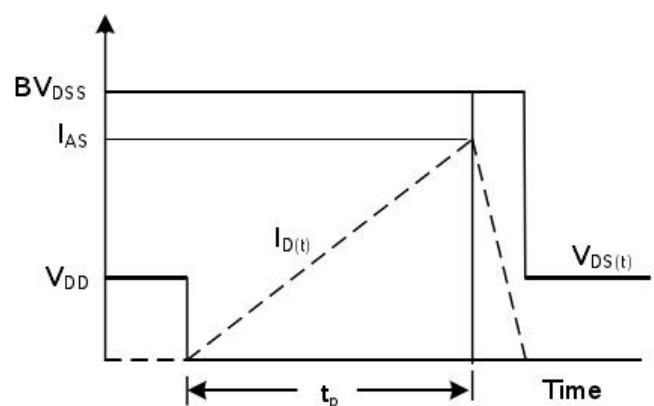
Gate Charge Test Circuit



Gate Charge Waveform



Unclamped Inductive Switching Test Circuit



Unclamped Inductive Switching Waveforms

RATING AND CHARACTERISTIC CURVES

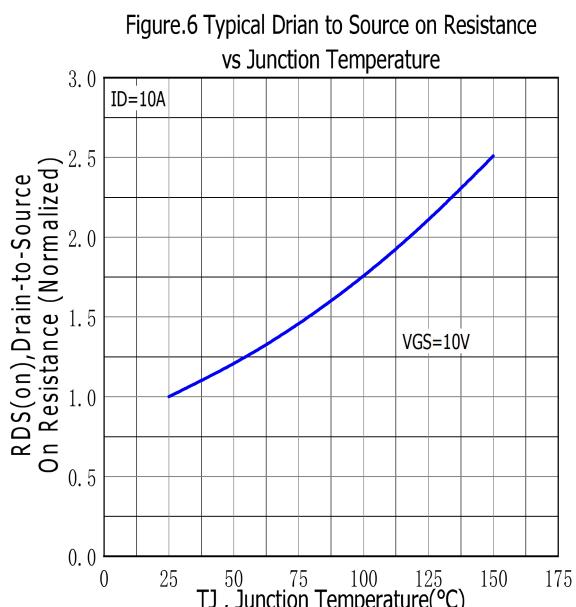
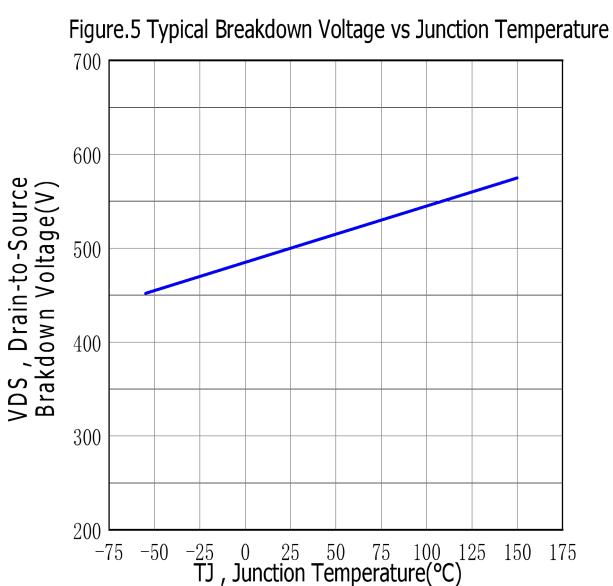
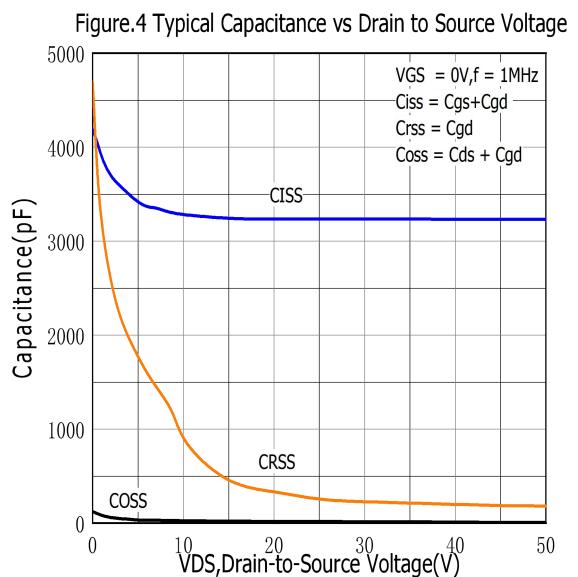
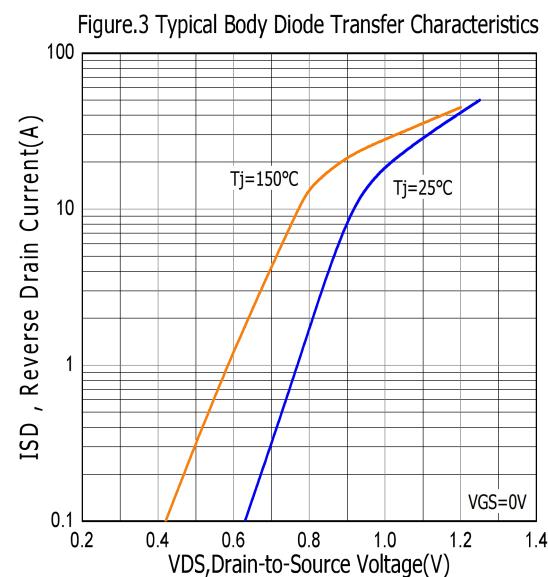
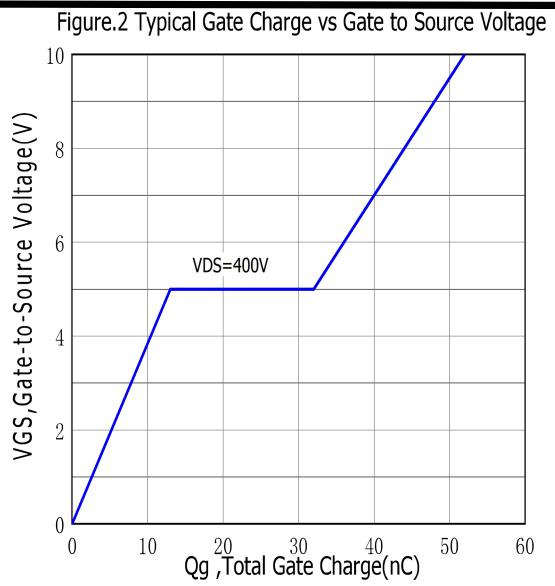
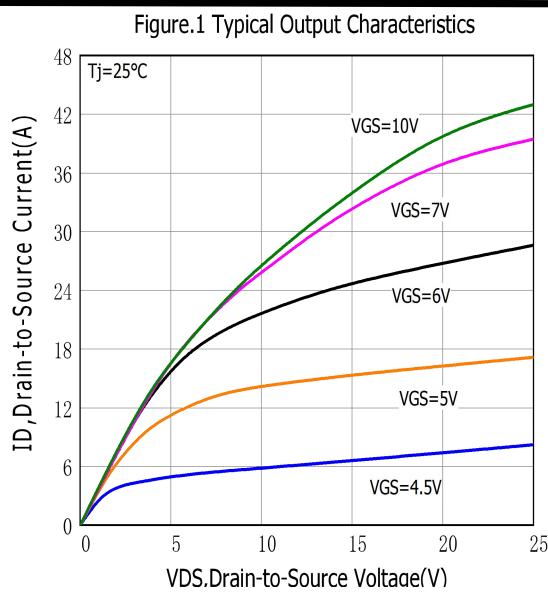


Figure.7 Maximum Forward Bias Safe Operating Area

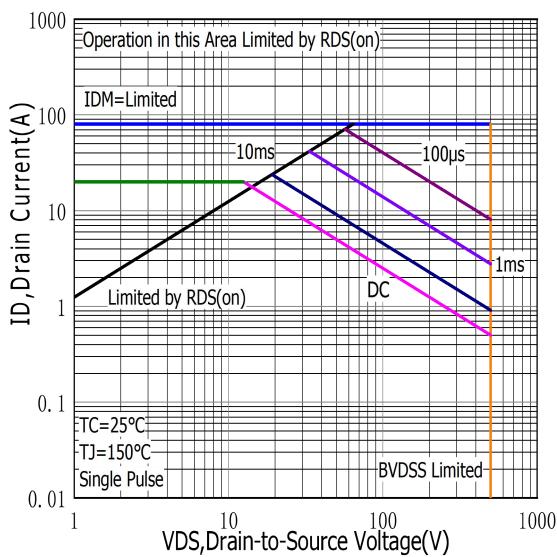


Figure.8 Typical Drain to Source ON Resistance vs Drain Current

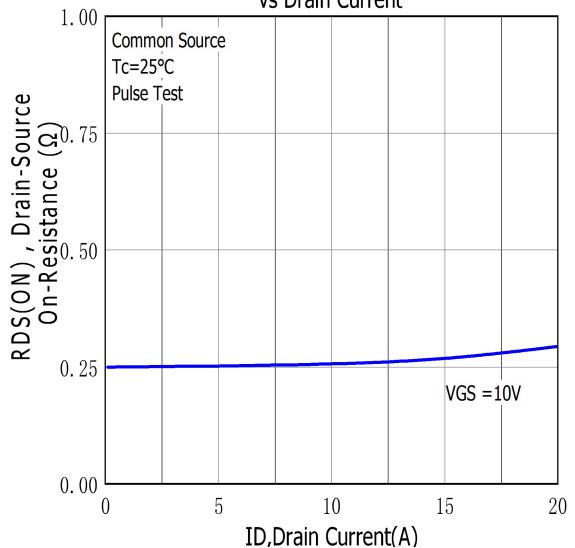


Figure.9 Maximum EAS vs Channel Temperature

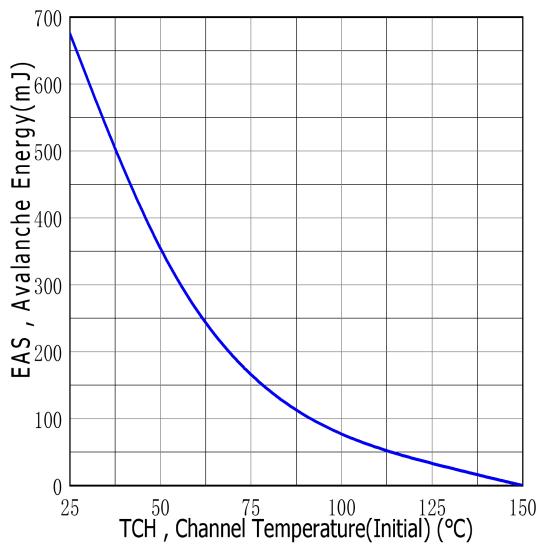


Figure.10 Typical Threshold Voltage vs Case Temperature

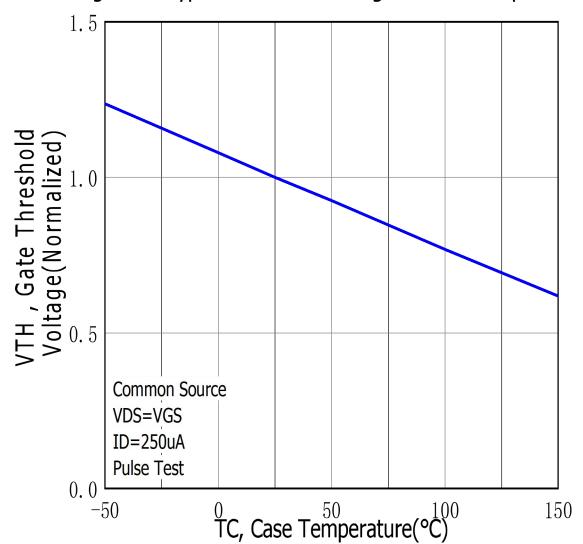


Figure.11 Maximum Effective Thermal Impedance , Junction to Case

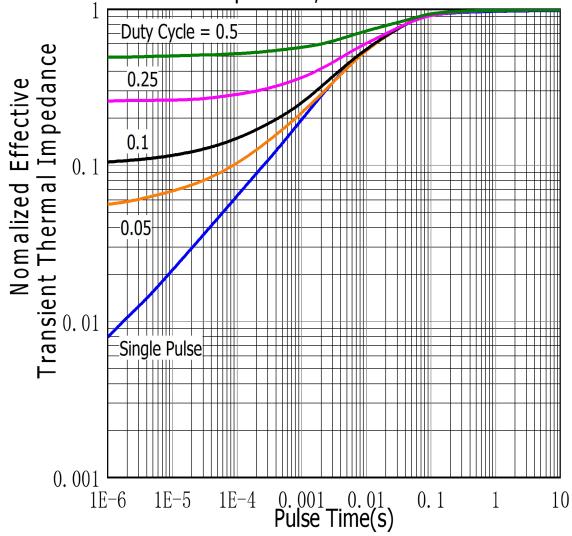
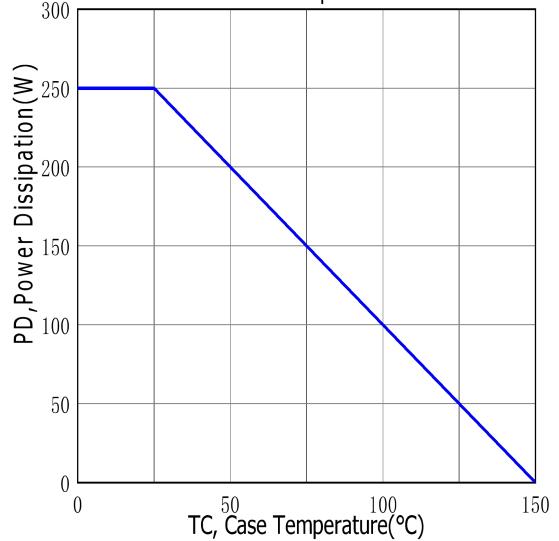
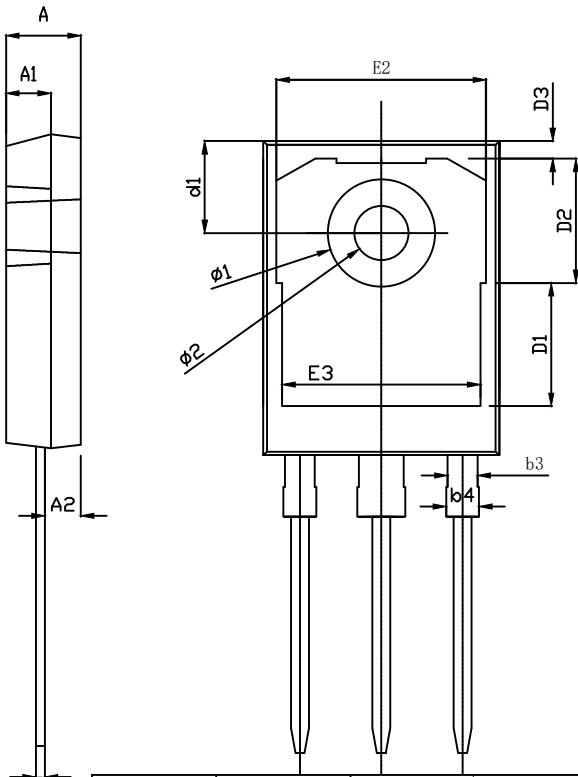
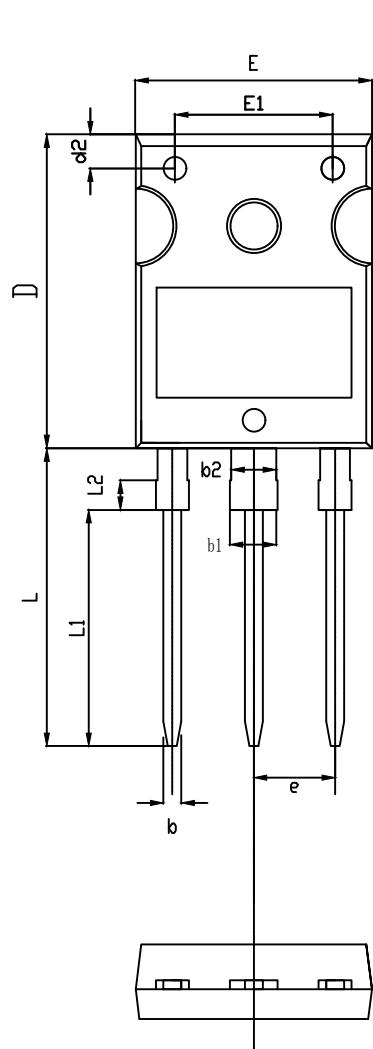


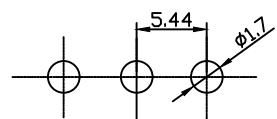
Figure.12 Maximum Power Dissipation vs Case Temperature



TO-247-3L PACKAGE OUTLINE



RECOMMENDED LAND PATTERN



UNIT: mm

	MIN	NOM	MAX
A	4.80	5.00	5.20
A1	2.80	3.00	3.20
A2	2.26	2.41	2.56
b	1.10	1.20	1.30
b1	2.90	—	3.20
b2	2.90	3.00	3.10
b3	1.90	2.00	2.10
b4	2.00	—	2.20
c	0.50	0.60	0.70
D	20.80	21.00	21.20
D1	8.03	8.23	8.43
D2	8.12	8.32	8.52
D3	0.97	1.17	1.37
d1	6.00	6.15	6.30
d2	2.20	2.30	2.40
E	15.60	15.80	16.00
E1	10.30	10.50	10.70
E2	13.82	14.02	14.22
E3	13.30	13.50	13.70
e	5.34	5.44	5.54
L	19.72	19.92	20.12
L1	15.59	15.79	15.99
L2	1.78	1.98	2.18
ø1	7.10	7.19	7.30
ø2	3.50	3.60	3.70